

# 74AVCH4T245

4-bit dual supply translating transceiver with configurable voltage translation; 3-state

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Product data sheet

## 1. General description

The 74AVCH4T245 is a 4-bit, dual supply transceiver that enables bidirectional level translation. The device can be used as two 2-bit transceivers or as a 4-bit transceiver. It features two data input-output ports (nAn and nBn), a direction control input (nDIR), a output enable input ( $\overline{\text{nOE}}$ ) and dual supply pins ( $V_{\text{CC(A)}}$  and  $V_{\text{CC(B)}}$ ). Both  $V_{\text{CC(A)}}$  and  $V_{\text{CC(B)}}$  can be supplied at any voltage between 0.8 V and 3.6 V making the device suitable for translating between any of the low voltage nodes (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V). Pins nAn,  $\overline{\text{nOE}}$  and nDIR are referenced to  $V_{\text{CC(A)}}$  and pins nBn are referenced to  $V_{\text{CC(B)}}$ . A HIGH on nDIR allows transmission from nAn to nBn and a LOW on nDIR allows transmission from nBn to nAn. The output enable input ( $\overline{\text{nOE}}$ ) can be used to disable the outputs so the buses are effectively isolated.

The device is fully specified for partial power-down applications using  $I_{\text{OFF}}$ . The  $I_{\text{OFF}}$  circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either  $V_{\text{CC(A)}}$  or  $V_{\text{CC(B)}}$  are at GND level, both A and B outputs are in the high-impedance OFF-state. The bus hold circuitry on the powered-up side always stays active.

The 74AVCH4T245 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

## 2. Features

- Wide supply voltage range:
  - ◆  $V_{\text{CC(A)}}$ : 0.8 V to 3.6 V
  - ◆  $V_{\text{CC(B)}}$ : 0.8 V to 3.6 V
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114E Class 3B exceeds 8000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101C exceeds 1000 V
- Maximum data rates:
  - ◆ 380 Mbit/s ( $\geq 1.8$  V to 3.3 V translation)

- ◆ 200 Mbit/s ( $\geq 1.1$  V to 3.3 V translation)
- ◆ 200 Mbit/s ( $\geq 1.1$  V to 2.5 V translation)
- ◆ 200 Mbit/s ( $\geq 1.1$  V to 1.8 V translation)
- ◆ 150 Mbit/s ( $\geq 1.1$  V to 1.5 V translation)
- ◆ 100 Mbit/s ( $\geq 1.1$  V to 1.2 V translation)
- Suspend mode
- Bus hold on data inputs
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C

### 3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74AVCH4T245D	$-40$ °C to $+125$ °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AVCH4T245PW	$-40$ °C to $+125$ °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AVCH4T245BQ	$-40$ °C to $+125$ °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1

### 4. Functional diagram

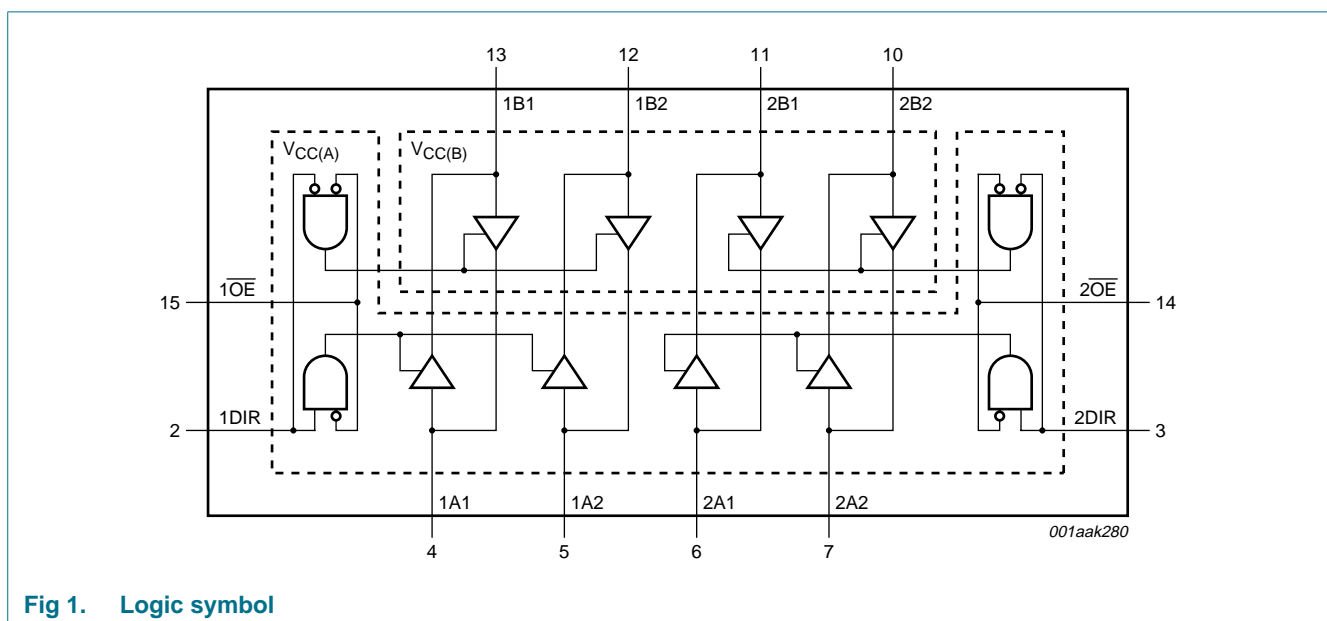


Fig 1. Logic symbol

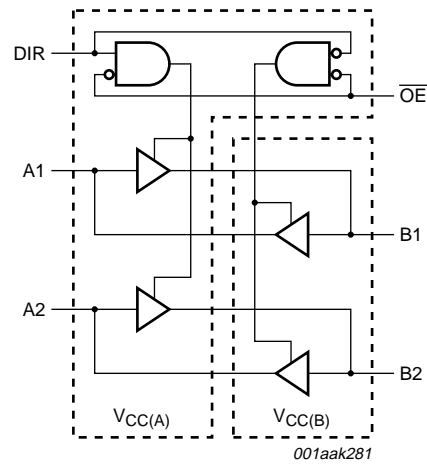


Fig 2. Logic diagram (one 2-bit transceiver)

## 5. Pinning information

### 5.1 Pinning

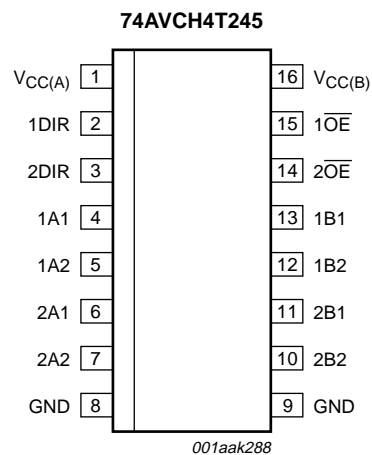


Fig 3. Pin configuration SOT109-1 (SO16)

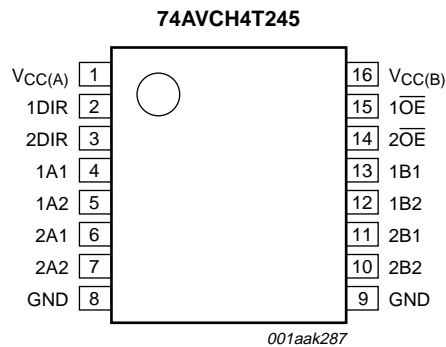
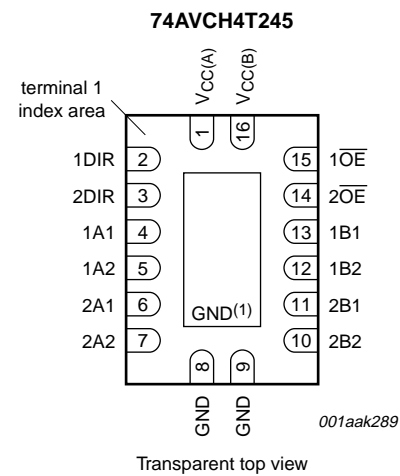


Fig 4. Pin configuration SOT403-1 (TSSOP16)



- (1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig 5. Pin configuration SOT763-1 (DHVQFN16)

## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{CC(A)}$	1	supply voltage A ( $nA_n$ , $n\overline{OE}$ and $nDIR$ inputs are referenced to $V_{CC(A)}$ )
1DIR, 2DIR	2, 3	direction control
1A1, 1A2	4, 5	data input or output
2A1, 2A2	6, 7	data input or output
GND <sup>[1]</sup>	8, 9	ground (0 V)
2B2, 2B1	10, 11	data input or output
1B2, 1B1	12, 13	data input or output
$2\overline{OE}$ , $1\overline{OE}$	14, 15	output enable input (active LOW)
$V_{CC(B)}$	16	supply voltage B ( $nB_n$ inputs are referenced to $V_{CC(B)}$ )

[1] All GND pins must be connected to ground (0 V).

## 6. Functional description

Table 3. Function table<sup>[1]</sup>

Supply voltage	Input		Input/output <sup>[3]</sup>	
$V_{CC(A)}$ , $V_{CC(B)}$	$\overline{nOE}$ <sup>[2]</sup>	$nDIR$ <sup>[2]</sup>	$nAn$ <sup>[2]</sup>	$nBn$ <sup>[2]</sup>
0.8 V to 3.6 V	L	L	$nAn = nBn$	input
0.8 V to 3.6 V	L	H	input	$nBn = nAn$
0.8 V to 3.6 V	H	X	Z	Z
GND <sup>[3]</sup>	X	X	Z	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] The  $nAn$ ,  $nDIR$  and  $\overline{nOE}$  input circuit is referenced to  $V_{CC(A)}$ ; The  $nBn$  input circuit is referenced to  $V_{CC(B)}$ .

[3] If at least one of  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into suspend mode.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+4.6	V
$V_{CC(B)}$	supply voltage B		-0.5	+4.6	V
$I_{IK}$	input clamping current	$V_I < 0$ V	-50	-	mA
$V_I$	input voltage		<sup>[1]</sup> -0.5	+4.6	V
$I_{OK}$	output clamping current	$V_O < 0$ V	-50	-	mA
$V_O$	output voltage	Active mode	<sup>[1][2][3]</sup> -0.5	$V_{CCO} + 0.5$	V
		Suspend or 3-state mode	<sup>[1]</sup> -0.5	+4.6	V
$I_O$	output current	$V_O = 0$ V to $V_{CCO}$	<sup>[2]</sup> -	$\pm 50$	mA
$I_{CC}$	supply current	$I_{CC(A)}$ or $I_{CC(B)}$	-	100	mA
$I_{GND}$	ground current		-100	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	<sup>[4]</sup> -	500	mW

[1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2]  $V_{CCO}$  is the supply voltage associated with the output port.

[3]  $V_{CCO} + 0.5$  V should not exceed 4.6 V.

[4] For SO16 package: above 70 °C the value of  $P_{tot}$  derates linearly at 8 mW/K.

For TSSOP16 package: above 60 °C the value of  $P_{tot}$  derates linearly at 5.5 mW/K.

For DHVQFN16 package: above 60 °C the value of  $P_{tot}$  derates linearly at 4.5 mW/K.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		0.8	3.6	V
$V_{CC(B)}$	supply voltage B		0.8	3.6	V
$V_I$	input voltage		0	3.6	V
$V_O$	output voltage	Active mode	[1] 0	$V_{CCO}$	V
		Suspend or 3-state mode	0	3.6	V
$T_{amb}$	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CCI} = 0.8 \text{ V to } 3.6 \text{ V}$	[2] -	5	ns/V

[1]  $V_{CCO}$  is the supply voltage associated with the output port.

[2]  $V_{CCI}$  is the supply voltage associated with the input port.

## 9. Static characteristics

**Table 6. Typical static characteristics at  $T_{amb} = 25 \text{ °C}$  [1][2]**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -1.5 \text{ mA}$ ; $V_{CC(A)} = V_{CC(B)} = 0.8 \text{ V}$	-	0.69	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 1.5 \text{ mA}$ ; $V_{CC(A)} = V_{CC(B)} = 0.8 \text{ V}$	-	0.07	-	V
$I_I$	input leakage current	nDIR, n $\overline{OE}$ input; $V_I = 0 \text{ V or } 3.6 \text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	$\pm 0.025$	$\pm 0.25$	$\mu\text{A}$
$I_{BHL}$	bus hold LOW current	A or B port; $V_I = 0.42 \text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$	[3] -	26	-	$\mu\text{A}$
$I_{BHH}$	bus hold HIGH current	A or B port; $V_I = 0.78 \text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$	[4] -	-24	-	$\mu\text{A}$
$I_{BHLO}$	bus hold LOW overdrive current	A or B port; $V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$	[5] -	27	-	$\mu\text{A}$
$I_{BHHO}$	bus hold HIGH overdrive current	A or B port; $V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$	[6] -	-26	-	$\mu\text{A}$
$I_{OZ}$	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CC(A)} = V_{CC(B)} = 3.6 \text{ V}$	[7] -	$\pm 0.5$	$\pm 2.5$	$\mu\text{A}$
		suspend mode A port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CC(A)} = 3.6 \text{ V}$ ; $V_{CC(B)} = 0 \text{ V}$	[7] -	$\pm 0.5$	$\pm 2.5$	$\mu\text{A}$
		suspend mode B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CC(A)} = 0 \text{ V}$ ; $V_{CC(B)} = 3.6 \text{ V}$	[7] -	$\pm 0.5$	$\pm 2.5$	$\mu\text{A}$
$I_{OFF}$	power-off leakage current	A port; $V_I$ or $V_O = 0 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(A)} = 0 \text{ V}$ ; $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	$\pm 0.1$	$\pm 1$	$\mu\text{A}$
		B port; $V_I$ or $V_O = 0 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(B)} = 0 \text{ V}$ ; $V_{CC(A)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	$\pm 0.1$	$\pm 1$	$\mu\text{A}$

**Table 6.** Typical static characteristics at  $T_{amb} = 25\text{ °C}$  [1][2] ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$C_I$	input capacitance	nDIR, n $\overline{OE}$ input; $V_I = 0\text{ V}$ or $3.3\text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 3.3\text{ V}$	-	1.0	-	pF
$C_{I/O}$	input/output capacitance	A and B port; $V_O = 3.3\text{ V}$ or $0\text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 3.3\text{ V}$	-	4.0	-	pF

[1]  $V_{CCO}$  is the supply voltage associated with the output port.[2]  $V_{CCI}$  is the supply voltage associated with the data input port.[3] The bus hold circuit can sink at least the minimum low sustaining current at  $V_{IL}$  max.  $I_{BHL}$  should be measured after lowering  $V_I$  to GND and then raising it to  $V_{IL}$  max.[4] The bus hold circuit can source at least the minimum high sustaining current at  $V_{IH}$  min.  $I_{BHH}$  should be measured after raising  $V_I$  to  $V_{CC}$  and then lowering it to  $V_{IH}$  min.[5] An external driver must source at least  $I_{BHLO}$  to switch this node from LOW to HIGH.[6] An external driver must sink at least  $I_{BHHO}$  to switch this node from HIGH to LOW.[7] For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.**Table 7.** Static characteristics [1][2]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Max	Min	Max		
$V_{IH}$	HIGH-level input voltage	data input						
		$V_{CCI} = 0.8\text{ V}$	$0.70V_{CCI}$	-	$0.70V_{CCI}$	-	V	
		$V_{CCI} = 1.1\text{ V}$ to $1.95\text{ V}$	$0.65V_{CCI}$	-	$0.65V_{CCI}$	-	V	
		$V_{CCI} = 2.3\text{ V}$ to $2.7\text{ V}$	1.6	-	1.6	-	V	
		$V_{CCI} = 3.0\text{ V}$ to $3.6\text{ V}$	2	-	2	-	V	
		nDIR, n $\overline{OE}$ input						
		$V_{CC(A)} = 0.8\text{ V}$	$0.70V_{CC(A)}$	-	$0.70V_{CC(A)}$	-	V	
		$V_{CC(A)} = 1.1\text{ V}$ to $1.95\text{ V}$	$0.65V_{CC(A)}$	-	$0.65V_{CC(A)}$	-	V	
	$V_{CC(A)} = 2.3\text{ V}$ to $2.7\text{ V}$	1.6	-	1.6	-	V		
	$V_{CC(A)} = 3.0\text{ V}$ to $3.6\text{ V}$	2	-	2	-	V		
	$V_{IL}$	LOW-level input voltage	data input					
			$V_{CCI} = 0.8\text{ V}$	-	$0.30V_{CCI}$	-	$0.30V_{CCI}$	V
$V_{CCI} = 1.1\text{ V}$ to $1.95\text{ V}$			-	$0.35V_{CCI}$	-	$0.35V_{CCI}$	V	
$V_{CCI} = 2.3\text{ V}$ to $2.7\text{ V}$			-	0.7	-	0.7	V	
$V_{CCI} = 3.0\text{ V}$ to $3.6\text{ V}$			-	0.8	-	0.8	V	
nDIR, n $\overline{OE}$ input								
$V_{CC(A)} = 0.8\text{ V}$			-	$0.30V_{CC(A)}$	-	$0.30V_{CC(A)}$	V	
$V_{CC(A)} = 1.1\text{ V}$ to $1.95\text{ V}$			-	$0.35V_{CC(A)}$	-	$0.35V_{CC(A)}$	V	
$V_{CC(A)} = 2.3\text{ V}$ to $2.7\text{ V}$		-	0.7	-	0.7	V		
$V_{CC(A)} = 3.0\text{ V}$ to $3.6\text{ V}$		-	0.8	-	0.8	V		

**Table 7. Static characteristics ...continued** [\[1\]\[2\]](#)

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = -100 μA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0.8 V to 3.6 V	V <sub>CCO</sub> - 0.1	-	V <sub>CCO</sub> - 0.1	-	V
		I <sub>O</sub> = -3 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.1 V	0.85	-	0.85	-	V
		I <sub>O</sub> = -6 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.4 V	1.05	-	1.05	-	V
		I <sub>O</sub> = -8 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.65 V	1.2	-	1.2	-	V
		I <sub>O</sub> = -9 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.3 V	1.75	-	1.75	-	V
		I <sub>O</sub> = -12 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.0 V	2.3	-	2.3	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = 100 μA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	0.1	-	0.1	V
		I <sub>O</sub> = 3 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.1 V	-	0.25	-	0.25	V
		I <sub>O</sub> = 6 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.4 V	-	0.35	-	0.35	V
		I <sub>O</sub> = 8 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.65 V	-	0.45	-	0.45	V
		I <sub>O</sub> = 9 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.3 V	-	0.55	-	0.55	V
		I <sub>O</sub> = 12 mA; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.0 V	-	0.7	-	0.7	V
I <sub>I</sub>	input leakage current	nDIR, nOE input; V <sub>I</sub> = 0 V or 3.6 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	±1	-	±5	μA
I <sub>BHL</sub>	bus hold LOW current	A or B port <a href="#">[3]</a>					
		V <sub>I</sub> = 0.49 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.4 V	15	-	15	-	μA
		V <sub>I</sub> = 0.58 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.65 V	25	-	25	-	μA
		V <sub>I</sub> = 0.70 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.3 V	45	-	45	-	μA
		V <sub>I</sub> = 0.80 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.0 V	100	-	90	-	μA



**Table 7. Static characteristics ...continued** [1][2]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
I <sub>BHH</sub>	bus hold HIGH current	A or B port [4]					
		V <sub>I</sub> = 0.91 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.4 V	-15	-	-15	-	μA
		V <sub>I</sub> = 1.07 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.65 V	-25	-	-25	-	μA
		V <sub>I</sub> = 1.60 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.3 V	-45	-	-45	-	μA
		V <sub>I</sub> = 2.00 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.0 V	-100	-	-100	-	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	A or B port [5]					
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.6 V	125	-	125	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.95 V	200	-	200	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.7 V	300	-	300	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.6 V	500	-	500	-	μA
I <sub>BHHO</sub>	bus hold HIGH overdrive current	A or B port [6]					
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.6 V	-125	-	-125	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 1.95 V	-200	-	-200	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 2.7 V	-300	-	-300	-	μA
		V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.6 V	-500	-	-500	-	μA
I <sub>OZ</sub>	OFF-state output current	A or B port; V <sub>O</sub> = 0 V or V <sub>CCO</sub> ; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.6 V [7]	-	±5	-	±30	μA
		suspend mode A port; V <sub>O</sub> = 0 V or V <sub>CCO</sub> ; V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(B)</sub> = 0 V [7]	-	±5	-	±30	μA
		suspend mode B port; V <sub>O</sub> = 0 V or V <sub>CCO</sub> ; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 3.6 V [7]	-	±5	-	±30	μA
I <sub>OFF</sub>	power-off leakage current	A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	±5	-	±30	μA
		B port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 0.8 V to 3.6 V	-	±5	-	±30	μA

**Table 7. Static characteristics ...continued** [1][2]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
I <sub>CC</sub>	supply current	A port; V <sub>I</sub> = 0 V or V <sub>CCI</sub> ; I <sub>O</sub> = 0 A					
		V <sub>CC(A)</sub> = 0.8 V to 3.6 V; V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	10	-	55	μA
		V <sub>CC(A)</sub> = 1.1 V to 3.6 V; V <sub>CC(B)</sub> = 1.1 V to 3.6 V	-	8	-	50	μA
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(B)</sub> = 0 V	-	8	-	50	μA
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 3.6 V	-2	-	-12	-	μA
		B port; V <sub>I</sub> = 0 V or V <sub>CCI</sub> ; I <sub>O</sub> = 0 A					
		V <sub>CC(A)</sub> = 0.8 V to 3.6 V; V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	10	-	55	μA
		V <sub>CC(A)</sub> = 1.1 V to 3.6 V; V <sub>CC(B)</sub> = 1.1 V to 3.6 V	-	8	-	50	μA
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(B)</sub> = 0 V	-2	-	-12	-	μA
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 3.6 V	-	8	-	50	μA
	A plus B port (I <sub>CC(A)</sub> + I <sub>CC(B)</sub> ); I <sub>O</sub> = 0 A; V <sub>I</sub> = 0 V or V <sub>CCI</sub> ; V <sub>CC(A)</sub> = 0.8 V to 3.6 V; V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	20	-	70	μA	
	A plus B port (I <sub>CC(A)</sub> + I <sub>CC(B)</sub> ); I <sub>O</sub> = 0 A; V <sub>I</sub> = 0 V or V <sub>CCI</sub> ; V <sub>CC(A)</sub> = 1.1 V to 3.6 V; V <sub>CC(B)</sub> = 1.1 V to 3.6 V	-	16	-	65	μA	

[1] V<sub>CCO</sub> is the supply voltage associated with the output port.[2] V<sub>CCI</sub> is the supply voltage associated with the data input port.[3] The bus hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>I</sub> to GND and then raising it to V<sub>IL</sub> max.[4] The bus hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub> min. I<sub>BHH</sub> should be measured after raising V<sub>I</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub> min.[5] An external driver must source at least I<sub>BHLO</sub> to switch this node from LOW to HIGH.[6] An external driver must sink at least I<sub>BHHO</sub> to switch this node from HIGH to LOW.[7] For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.**Table 8. Typical total supply current (I<sub>CC(A)</sub> + I<sub>CC(B)</sub>)**

V <sub>CC(A)</sub>	V <sub>CC(B)</sub>							Unit
	0 V	0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
0 V	0	0.1	0.1	0.1	0.1	0.1	0.1	μA
0.8 V	0.1	0.1	0.1	0.1	0.1	0.3	1.6	μA
1.2 V	0.1	0.1	0.1	0.1	0.1	0.1	0.8	μA
1.5 V	0.1	0.1	0.1	0.1	0.1	0.1	0.4	μA
1.8 V	0.1	0.1	0.1	0.1	0.1	0.1	0.2	μA
2.5 V	0.1	0.3	0.1	0.1	0.1	0.1	0.1	μA
3.3 V	0.1	1.6	0.8	0.4	0.2	0.1	0.1	μA

## 10. Dynamic characteristics

**Table 9.** Typical power dissipation capacitance at  $V_{CC(A)} = V_{CC(B)}$  and  $T_{amb} = 25\text{ °C}$  [1][2]

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
$C_{PD}$	power dissipation capacitance	A port: (direction nAn to nBn); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		A port: (direction nAn to nBn); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		A port: (direction nBn to nAn); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		A port: (direction nBn to nAn); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction nAn to nBn); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		B port: (direction nAn to nBn); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction nBn to nAn); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		B port: (direction nBn to nAn); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2]  $f_i = 10\text{ MHz}$ ;  $V_i = \text{GND to } V_{CC}$ ;  $t_r = t_f = 1\text{ ns}$ ;  $C_L = 0\text{ pF}$ ;  $R_L = \infty\ \Omega$ .

**Table 10. Typical dynamic characteristics at  $V_{CC(A)} = 0.8\text{ V}$  and  $T_{amb} = 25\text{ °C}$  [1]**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#); for wave forms see [Figure 6](#) and [Figure 7](#)

Symbol	Parameter	Conditions	$V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
$t_{pd}$	propagation delay	nAn to nBn	14.5	7.3	6.5	6.2	5.9	6.0	ns
		nBn to nAn	14.5	12.7	12.4	12.3	12.1	12.0	ns
$t_{dis}$	disable time	$n\overline{OE}$ to nAn	14.3	14.3	14.3	14.3	14.3	14.3	ns
		$n\overline{OE}$ to nBn	17.0	9.9	9.0	9.4	9.0	9.7	ns
$t_{en}$	enable time	$n\overline{OE}$ to nAn	18.2	18.2	18.2	18.2	18.2	18.2	ns
		$n\overline{OE}$ to nBn	19.2	10.7	9.8	9.6	9.7	10.2	ns

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ ;  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .**Table 11. Typical dynamic characteristics at  $V_{CC(B)} = 0.8\text{ V}$  and  $T_{amb} = 25\text{ °C}$  [1]**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#); for wave forms see [Figure 6](#) and [Figure 7](#)

Symbol	Parameter	Conditions	$V_{CC(A)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
$t_{pd}$	propagation delay	nAn to nBn	14.5	12.7	12.4	12.3	12.1	12.0	ns
		nBn to nAn	14.5	7.3	6.5	6.2	5.9	6.0	ns
$t_{dis}$	disable time	$n\overline{OE}$ to nAn	14.3	5.5	4.1	4.0	3.0	3.5	ns
		$n\overline{OE}$ to nBn	17.0	13.8	13.4	13.1	12.9	12.7	ns
$t_{en}$	enable time	$n\overline{OE}$ to nAn	18.2	5.6	4.0	3.2	2.4	2.2	ns
		$n\overline{OE}$ to nBn	19.2	14.6	14.1	13.9	13.7	13.6	ns

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ ;  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .

**Table 12. Dynamic characteristics for temperature range –40 °C to +85 °C [1]**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#); for wave forms see [Figure 6](#) and [Figure 7](#).

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>										Unit
			1.2 V ± 0.1 V		1.5 V ± 0.1 V		1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 1.1 V to 1.3 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.5	9.4	0.5	7.1	0.5	6.2	0.5	5.2	0.5	5.1	ns
		nBn to nAn	0.5	9.4	0.5	8.9	0.5	8.7	0.5	8.4	0.5	8.2	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	10.9	1.8	10.9	1.8	10.9	1.8	10.9	1.8	10.9	ns
		n $\overline{\text{OE}}$ to nBn	1.9	12.4	1.9	9.6	1.9	9.5	1.4	8.1	1.2	9.1	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.4	12.8	1.4	12.8	1.4	12.8	1.4	12.8	1.4	12.8	ns
		n $\overline{\text{OE}}$ to nBn	1.1	13.3	1.1	10.0	1.1	8.9	1.0	7.9	1.0	7.7	ns
<b>V<sub>CC(A)</sub> = 1.4 V to 1.6 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.3	8.9	0.3	6.3	0.3	5.2	0.3	4.2	0.3	4.2	ns
		nBn to nAn	0.7	7.1	0.7	6.3	0.5	6.0	0.4	5.7	0.3	5.6	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	10.2	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	ns
		n $\overline{\text{OE}}$ to nBn	1.9	11.3	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.1	9.4	1.4	9.4	1.1	9.4	0.7	9.4	0.4	9.4	ns
		n $\overline{\text{OE}}$ to nBn	1.4	12.1	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	ns
<b>V<sub>CC(A)</sub> = 1.65 V to 1.95 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	8.7	0.1	6.0	0.1	4.9	0.1	3.9	0.3	3.9	ns
		nBn to nAn	0.6	6.2	0.6	5.3	0.5	4.9	0.3	4.6	0.3	4.5	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	8.6	1.6	8.6	1.8	8.6	1.3	8.6	1.6	8.6	ns
		n $\overline{\text{OE}}$ to nBn	1.7	10.9	1.7	9.9	1.6	8.7	1.2	6.9	1.0	6.9	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.0	7.2	1.0	7.2	1.0	7.2	0.6	7.2	0.4	7.2	ns
		n $\overline{\text{OE}}$ to nBn	1.2	11.7	1.2	9.2	1.0	7.4	0.8	5.3	0.8	4.6	ns
<b>V<sub>CC(A)</sub> = 2.3 V to 2.7 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	8.4	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	ns
		nBn to nAn	0.6	5.2	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.0	6.2	1.0	6.2	1.0	6.2	1.0	6.2	1.0	6.2	ns
		n $\overline{\text{OE}}$ to nBn	1.5	10.4	1.5	8.8	1.3	8.2	1.1	6.2	0.9	5.2	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	0.7	4.8	0.7	4.8	0.7	4.8	0.6	4.8	0.4	4.8	ns
		n $\overline{\text{OE}}$ to nBn	0.9	11.3	0.9	8.8	0.8	7.0	0.6	4.8	0.6	4.0	ns
<b>V<sub>CC(A)</sub> = 3.0 V to 3.6 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	8.2	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	ns
		nBn to nAn	0.6	5.1	0.6	4.2	0.4	3.4	0.2	3.0	0.1	2.8	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	0.7	5.6	0.7	5.6	0.7	5.6	0.7	5.6	0.7	5.6	ns
		n $\overline{\text{OE}}$ to nBn	1.4	10.2	1.4	9.3	1.2	8.1	1.0	6.4	0.8	6.2	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	0.6	3.8	0.6	3.8	0.6	3.8	0.6	3.8	0.4	3.8	ns
		n $\overline{\text{OE}}$ to nBn	0.8	11.3	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	ns

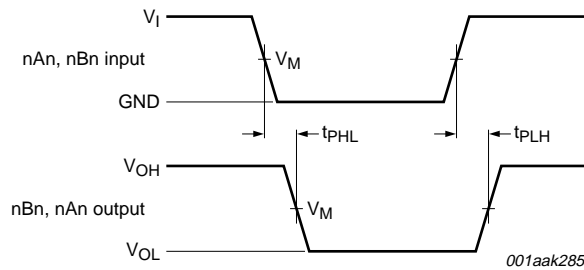
[1] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>; t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>; t<sub>en</sub> is the same as t<sub>PZL</sub> and t<sub>PZH</sub>.

**Table 13. Dynamic characteristics for temperature range –40 °C to +125 °C [1]**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#); for wave forms see [Figure 6](#) and [Figure 7](#)

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>										Unit
			1.2 V ± 0.1 V		1.5 V ± 0.1 V		1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 1.1 V to 1.3 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.5	10.4	0.5	7.9	0.5	6.9	0.5	5.8	0.5	5.7	ns
		nBn to nAn	0.5	10.4	0.5	9.8	0.5	9.6	0.5	9.3	0.5	9.1	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	12.0	1.8	12.0	1.8	12.0	1.8	12.0	1.8	12.0	ns
		n $\overline{\text{OE}}$ to nBn	1.9	13.7	1.9	10.6	1.9	10.5	1.4	9.0	1.2	10.1	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.4	14.1	1.4	14.1	1.4	14.1	1.4	14.1	1.4	14.1	ns
		n $\overline{\text{OE}}$ to nBn	1.1	14.7	1.1	11.0	1.1	9.8	1.0	8.7	1.0	8.5	ns
<b>V<sub>CC(A)</sub> = 1.4 V to 1.6 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.3	9.8	0.3	7.0	0.3	5.8	0.3	4.7	0.3	4.7	ns
		nBn to nAn	0.7	7.9	0.7	7.0	0.5	6.6	0.4	6.3	0.3	6.2	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	11.3	1.8	11.3	1.5	11.3	1.3	11.3	1.6	11.3	ns
		n $\overline{\text{OE}}$ to nBn	1.9	12.5	1.9	11.4	1.9	10.1	1.4	8.2	1.2	8.4	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.1	10.4	1.4	10.4	1.1	10.4	0.7	10.4	0.4	10.4	ns
		n $\overline{\text{OE}}$ to nBn	1.4	13.3	1.4	10.6	1.1	8.5	0.9	6.4	0.9	6.2	ns
<b>V<sub>CC(A)</sub> = 1.65 V to 1.95 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	9.6	0.1	6.6	0.1	5.4	0.1	4.3	0.3	4.3	ns
		nBn to nAn	0.6	6.9	0.6	5.9	0.5	5.4	0.3	5.1	0.3	5.0	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.8	9.5	1.6	9.5	1.8	9.5	1.3	9.5	1.6	9.5	ns
		n $\overline{\text{OE}}$ to nBn	1.7	12.0	1.7	10.9	1.6	9.6	1.2	7.6	1.0	7.6	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	1.0	8.0	1.0	8.0	1.0	8.0	0.6	8.0	0.4	8.0	ns
		n $\overline{\text{OE}}$ to nBn	1.2	12.9	1.2	10.2	1.0	8.2	0.8	5.9	0.8	5.1	ns
<b>V<sub>CC(A)</sub> = 2.3 V to 2.7 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	9.3	0.1	6.3	0.1	5.1	0.2	4.0	0.1	4.0	ns
		nBn to nAn	0.6	5.8	0.6	4.7	0.4	4.3	0.2	3.9	0.2	3.8	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	ns
		n $\overline{\text{OE}}$ to nBn	1.5	11.5	1.5	10.4	1.3	9.1	1.1	6.9	0.9	5.8	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	0.7	5.3	0.7	5.3	0.7	5.3	0.6	5.3	0.4	5.3	ns
		n $\overline{\text{OE}}$ to nBn	0.9	12.4	0.9	9.7	0.8	7.7	0.6	5.3	0.6	4.4	ns
<b>V<sub>CC(A)</sub> = 3.0 V to 3.6 V</b>													
t <sub>pd</sub>	propagation delay	nAn to Bn	0.1	9.1	0.1	6.2	0.1	5.0	0.1	3.8	0.1	3.3	ns
		nBn to nAn	0.6	5.7	0.6	4.7	0.4	3.9	0.2	3.4	0.1	3.3	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nAn	0.7	6.2	0.7	6.2	0.7	6.2	0.7	6.2	0.7	6.2	ns
		n $\overline{\text{OE}}$ to nBn	1.4	11.3	1.4	10.3	1.2	9.0	1.0	7.1	0.8	6.9	ns
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nAn	0.6	4.2	0.6	4.2	0.6	4.2	0.6	4.2	0.4	4.2	ns
		n $\overline{\text{OE}}$ to nBn	0.8	12.4	0.8	9.6	0.6	7.5	0.5	5.2	0.5	4.2	ns

[1] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>; t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>; t<sub>en</sub> is the same as t<sub>PZL</sub> and t<sub>PZH</sub>.

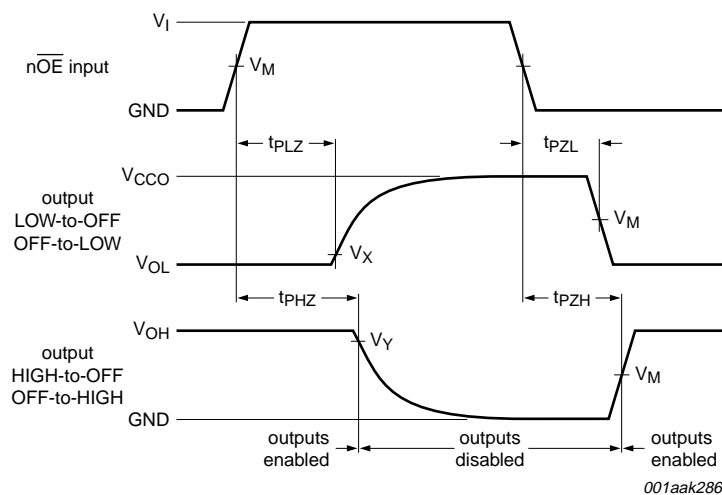
## 11. Waveforms



Measurement points are given in [Table 14](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 6. The data input (nAn, nBn) to output (nBn, nAn) propagation delay times**



Measurement points are given in [Table 14](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

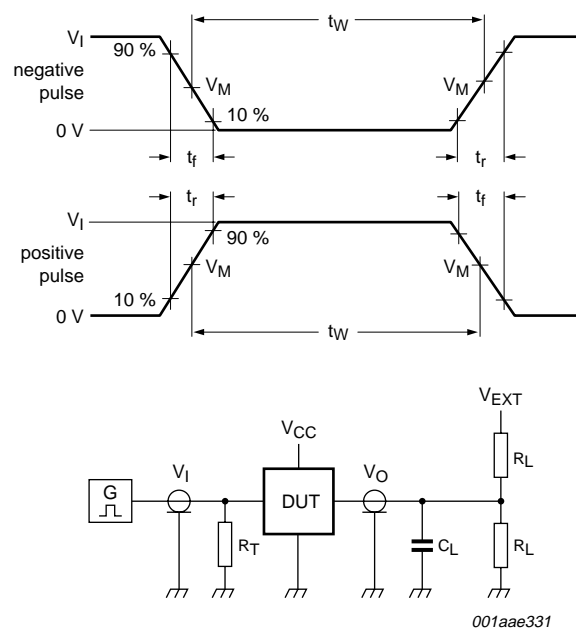
**Fig 7. Enable and disable times**

**Table 14. Measurement points**

Supply voltage	Input <sup>[1]</sup>		Output <sup>[2]</sup>		
	$V_{CC(A)}$ , $V_{CC(B)}$	$V_M$	$V_M$	$V_X$	$V_Y$
0.8 V to 1.6 V		$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.1 V$	$V_{OH} - 0.1 V$
1.65 V to 2.7 V		$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.15 V$	$V_{OH} - 0.15 V$
3.0 V to 3.6 V		$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$

[1]  $V_{CCI}$  is the supply voltage associated with the data input port.

[2]  $V_{CCO}$  is the supply voltage associated with the output port.



Test data is given in [Table 15](#).

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 8. Load circuit for switching times**

**Table 15. Test data**

Supply voltage $V_{CC(A)}, V_{CC(B)}$	Input		Load		$V_{EXT}$		
	$V_I$ <sup>[1]</sup>	$\Delta t/\Delta V$ <sup>[2]</sup>	$C_L$	$R_L$	$t_{PLH}, t_{PHL}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$ <sup>[3]</sup>
0.8 V to 1.6 V	$V_{CCI}$	$\leq 1.0$ ns/V	15 pF	2 k $\Omega$	open	GND	$2V_{CCO}$
1.65 V to 2.7 V	$V_{CCI}$	$\leq 1.0$ ns/V	15 pF	2 k $\Omega$	open	GND	$2V_{CCO}$
3.0 V to 3.6 V	$V_{CCI}$	$\leq 1.0$ ns/V	15 pF	2 k $\Omega$	open	GND	$2V_{CCO}$

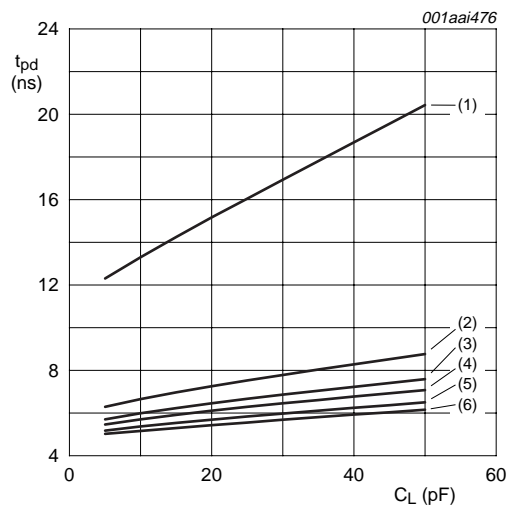
[1]  $V_{CCI}$  is the supply voltage associated with the data input port.

[2]  $dV/dt \geq 1.0$  V/ns

[3]  $V_{CCO}$  is the supply voltage associated with the output port.

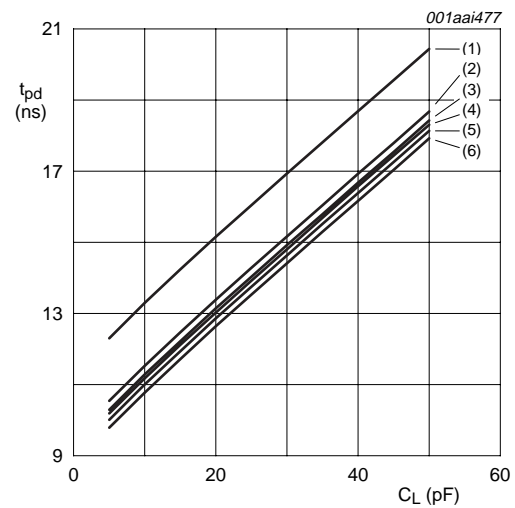


## 12. Typical propagation delay characteristics



a. Propagation delay (A to B);  $V_{CC(A)} = 0.8 \text{ V}$

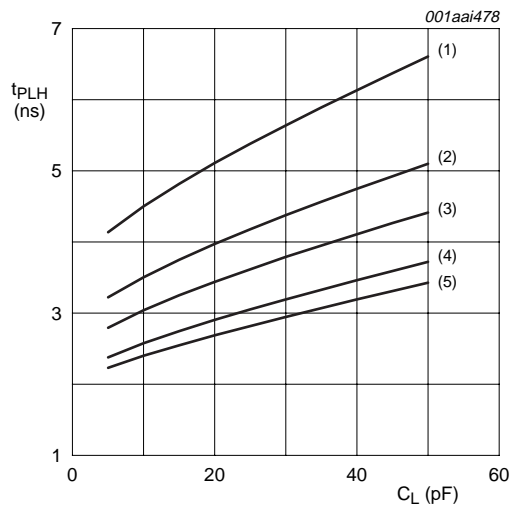
- (1)  $V_{CC(B)} = 0.8 \text{ V}$ .
- (2)  $V_{CC(B)} = 1.2 \text{ V}$ .
- (3)  $V_{CC(B)} = 1.5 \text{ V}$ .
- (4)  $V_{CC(B)} = 1.8 \text{ V}$ .
- (5)  $V_{CC(B)} = 2.5 \text{ V}$ .
- (6)  $V_{CC(B)} = 3.3 \text{ V}$ .



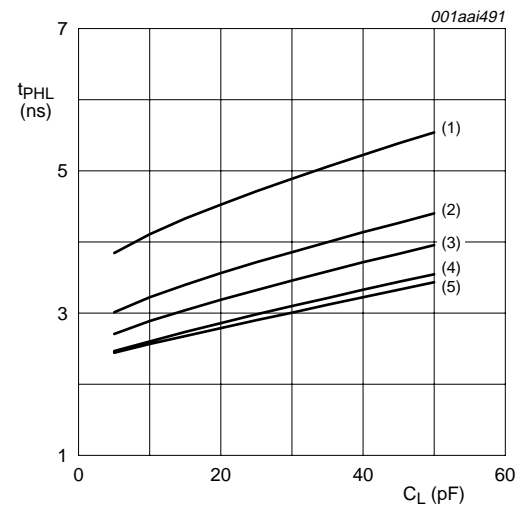
b. Propagation delay (A to B);  $V_{CC(B)} = 0.8 \text{ V}$

- (1)  $V_{CC(A)} = 0.8 \text{ V}$ .
- (2)  $V_{CC(A)} = 1.2 \text{ V}$ .
- (3)  $V_{CC(A)} = 1.5 \text{ V}$ .
- (4)  $V_{CC(A)} = 1.8 \text{ V}$ .
- (5)  $V_{CC(A)} = 2.5 \text{ V}$ .
- (6)  $V_{CC(A)} = 3.3 \text{ V}$ .

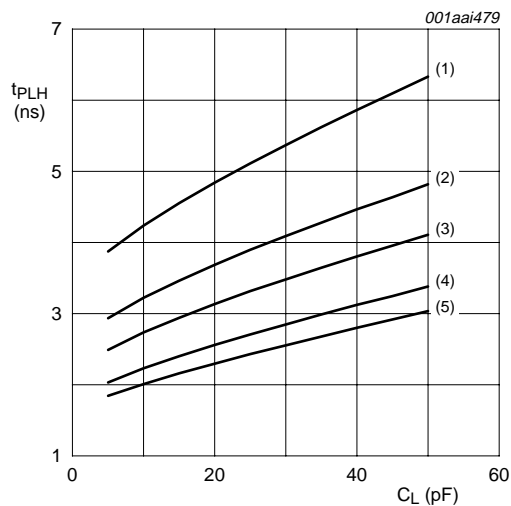
**Fig 9. Typical propagation delay versus load capacitance;  $T_{amb} = 25 \text{ }^\circ\text{C}$**



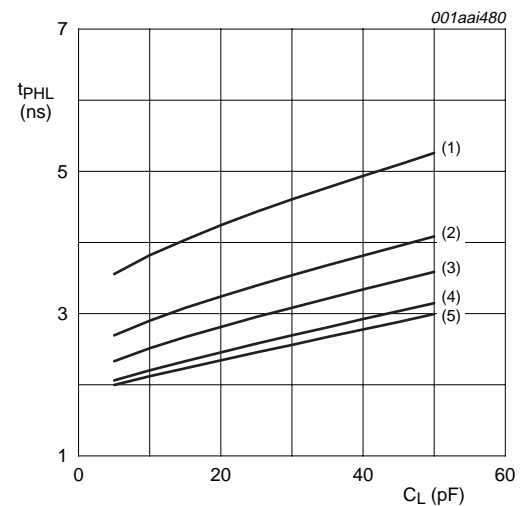
a. LOW to HIGH propagation delay (A to B);  
 $V_{CC(A)} = 1.2 \text{ V}$



b. HIGH to LOW propagation delay (A to B);  
 $V_{CC(A)} = 1.2 \text{ V}$



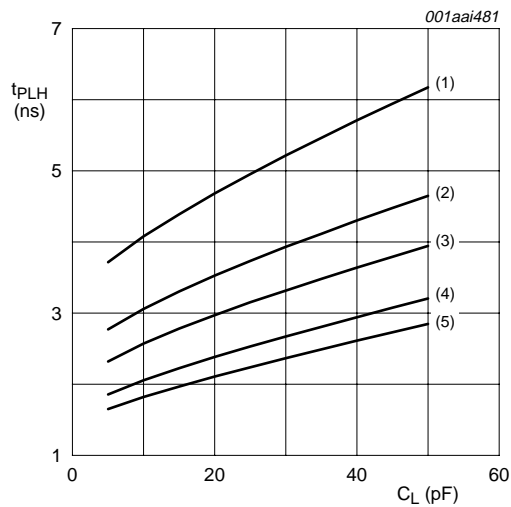
c. LOW to HIGH propagation delay (A to B);  
 $V_{CC(A)} = 1.5 \text{ V}$



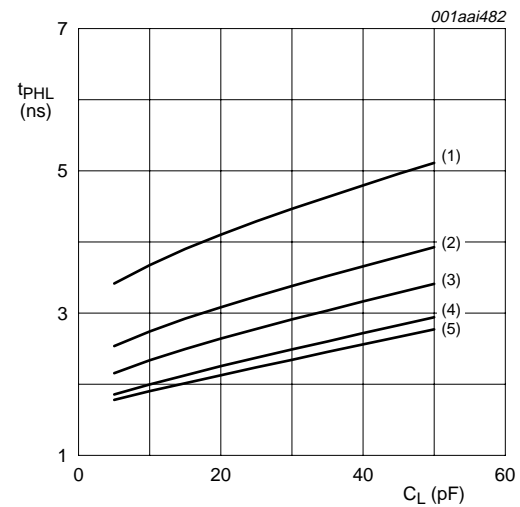
d. HIGH to LOW propagation delay (A to B);  
 $V_{CC(A)} = 1.5 \text{ V}$

- (1)  $V_{CC(B)} = 1.2 \text{ V}$ .
- (2)  $V_{CC(B)} = 1.5 \text{ V}$ .
- (3)  $V_{CC(B)} = 1.8 \text{ V}$ .
- (4)  $V_{CC(B)} = 2.5 \text{ V}$ .
- (5)  $V_{CC(B)} = 3.3 \text{ V}$ .

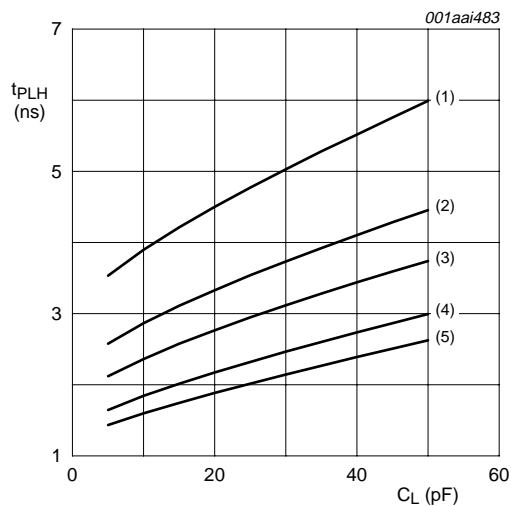
**Fig 10. Typical propagation delay versus load capacitance;  $T_{amb} = 25 \text{ }^\circ\text{C}$**



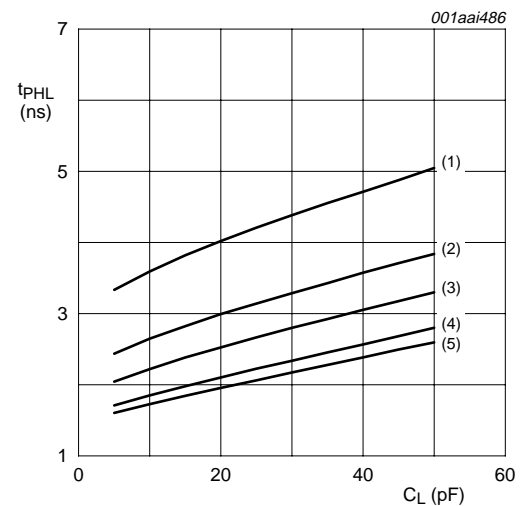
a. LOW to HIGH propagation delay (A to B);  
 $V_{CC(A)} = 1.8 \text{ V}$



b. HIGH to LOW propagation delay (A to B);  
 $V_{CC(A)} = 1.8 \text{ V}$



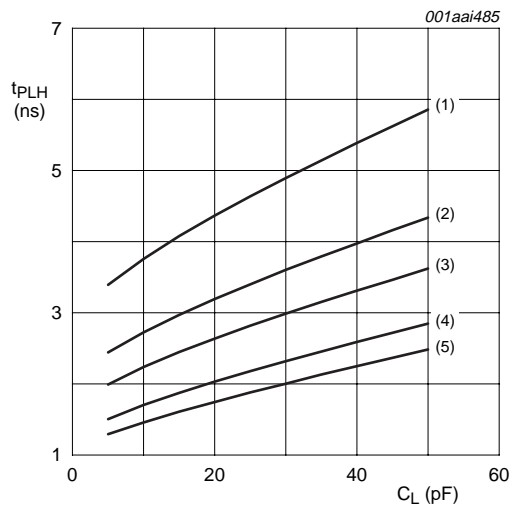
c. LOW to HIGH propagation delay (A to B);  
 $V_{CC(A)} = 2.5 \text{ V}$



d. HIGH to LOW propagation delay (A to B);  
 $V_{CC(A)} = 2.5 \text{ V}$

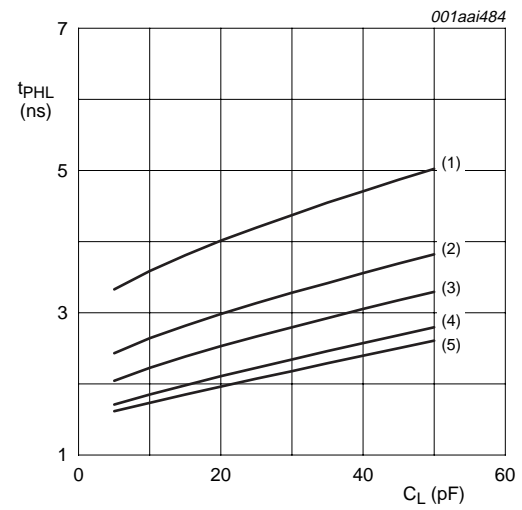
- (1)  $V_{CC(B)} = 1.2 \text{ V}$ .  
 (2)  $V_{CC(B)} = 1.5 \text{ V}$ .  
 (3)  $V_{CC(B)} = 1.8 \text{ V}$ .  
 (4)  $V_{CC(B)} = 2.5 \text{ V}$ .  
 (5)  $V_{CC(B)} = 3.3 \text{ V}$ .

Fig 11. Typical propagation delay versus load capacitance;  $T_{amb} = 25 \text{ }^\circ\text{C}$



a. LOW to HIGH propagation delay (A to B);  
 $V_{CC(A)} = 3.3 \text{ V}$

- (1)  $V_{CC(B)} = 1.2 \text{ V}$ .
- (2)  $V_{CC(B)} = 1.5 \text{ V}$ .
- (3)  $V_{CC(B)} = 1.8 \text{ V}$ .
- (4)  $V_{CC(B)} = 2.5 \text{ V}$ .
- (5)  $V_{CC(B)} = 3.3 \text{ V}$ .



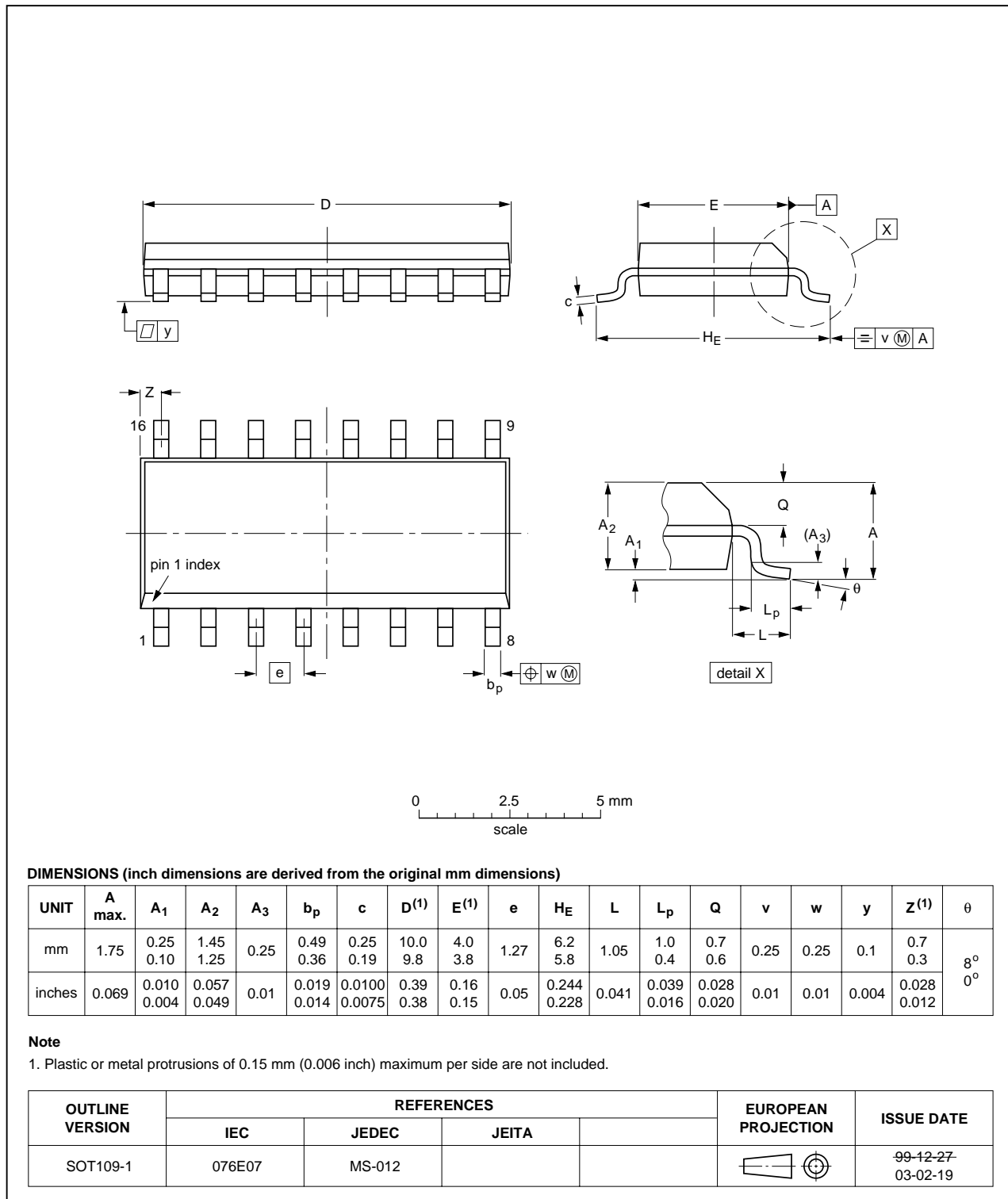
b. HIGH to LOW propagation delay (A to B);  
 $V_{CC(A)} = 3.3 \text{ V}$

**Fig 12. Typical propagation delay versus load capacitance;  $T_{amb} = 25 \text{ }^\circ\text{C}$**

## 13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

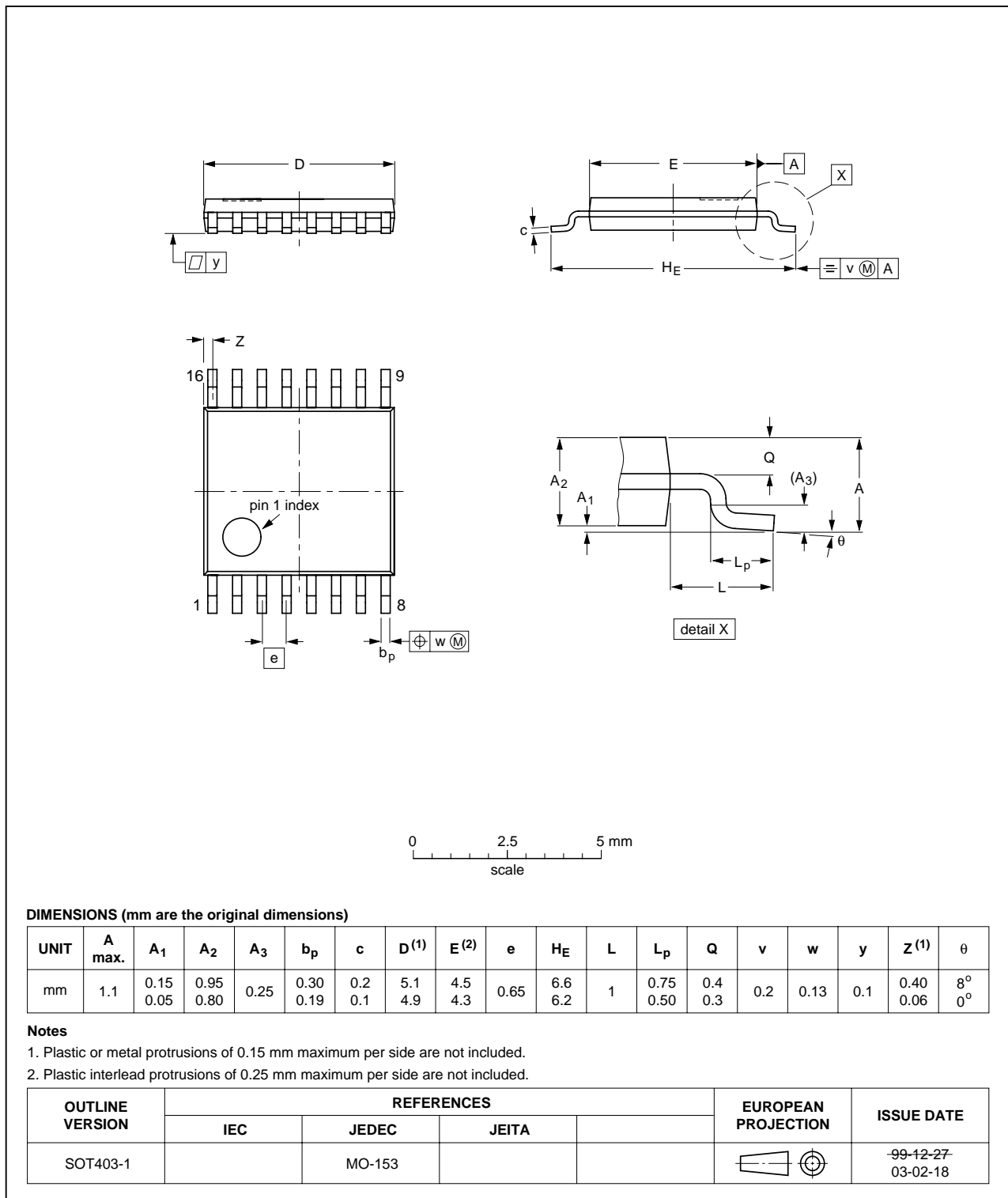
SOT109-1



www.DataSheet4U.com  
Fig 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

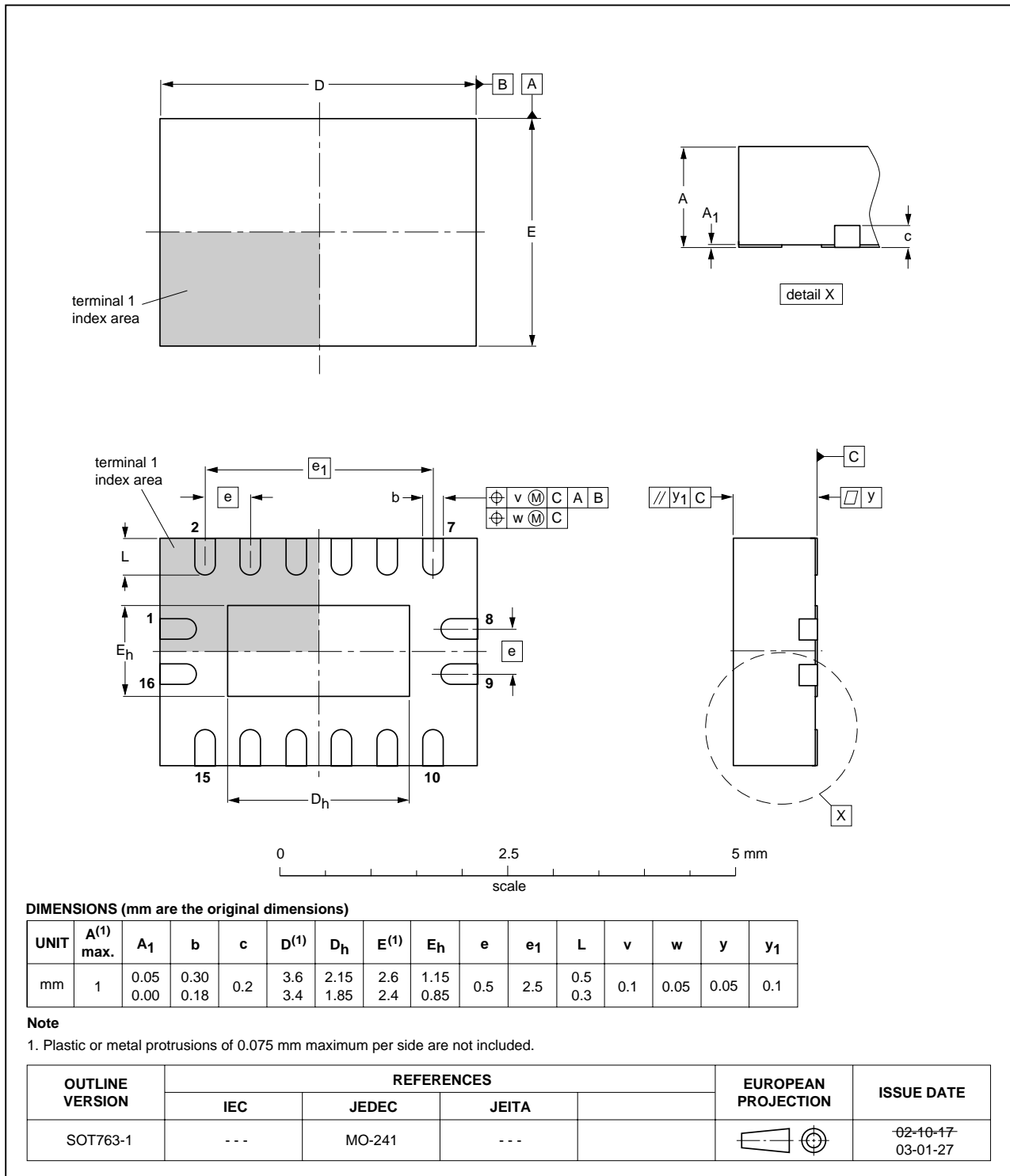
SOT403-1



www.DataSheet4U.com  
**Fig 14. Package outline SOT403-1 (TSSOP16)**

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1



## 14. Abbreviations

**Table 16. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 15. Revision history

**Table 17. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AVCH4T245_1	20090806	Product data sheet	-	-



## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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